

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L8	1349	glass adj substrate same gate same line same electrode same pixel adj electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 11:58
L9	1279	L8 and (lcd liquid adj crystal adj display)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 11:58
L10	681	L9 not (@rlad>"20011102" @ad>"20011102")	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/13 11:58
L11	681	L10	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/13 11:58
L12	430	L11 and (pattern\$3 etch\$3) same line same electrode	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	ON	2005/05/13 11:58
L13	14	L12 and pixel adj electrode adj3 ("on" "over" overlay\$3) adj2(passivation insulat\$3 dielectric protect\$3 silicon adj (nitride dioxide oxide) sin n>"sub. 4" sio2 siox "sio?sub.2")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 12:06
L14	9	L13 and (pattern\$3 etch\$3) same gate adj3 line same gate adj electrode	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	ON	2005/05/13 12:03
L15	368	(438/625).CCLS.	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/13 12:01
L17	1185	(pattern\$3 etch\$3) same gate adj3 line same gate adj electrode and "438"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	ON	2005/05/13 12:08
L18	22	17 and pixel adj electrode adj3 ("on" "over" overlay\$3) adj2(passivation insulat\$3 dielectric protect\$3 silicon adj (nitride dioxide oxide) sin n>"sub. 4" sio2 siox "sio?sub.2")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 12:28
L19	22	18 and (pattern\$3 etch\$3) same gate adj3 line same gate adj electrode and "438"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	ON	2005/05/13 12:12

L20	1185	17 and (pattern\$3 etch\$3) same gate adj3 line same gate adj electrode and "438"/\$.ccls.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	ON	2005/05/13 12:12
L22	22	17 and pixel adj electrode adj3 ("on" "over" overlay\$3) adj2 (passivation insulat\$3 dielectric protect\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 13:22
L23	21	22 and data	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 13:22
S1	1	("6706628").PN.	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/06 17:11
S2	3	((("6297441") or ("20020000382") or ("6403481"))).PN.	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/06 17:30
S3	27	((("6344364") or ("6348435") or ("6355524") or ("6379981") or ("6429109") or ("6458646") or ("6699777") or ("6630405") or ("5368686") or ("5,597,756") or ("5776823") or ("5891784") or ("5940315") or ("5989959") or ("6043561") or ("6063704") or ("6072223") or ("6075274") or ("6090660") or ("6097049") or ("6107145") or ("6121125") or ("6165883") or ("6232209") or ("6245605") or ("6268622") or ("6320246") or ("000001,")) .PN.	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/06 17:46
S4	1349	glass adj substrate same gate same line same electrode same pixel adj electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/12 18:15
S5	1279	S4 and (lcd liquid adj crystal adj display)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/12 14:30
S6	681	S5 not (@rlad>"20011102" @ad>"20011102")	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/12 18:14
S7	5	S6 and (seed\$4 nuclei nucleat\$3 initiat\$3) same (plat\$3 electroplat\$3)	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/05/12 14:33

S8	5	S7 and (seed\$4 nuclei nucleat\$3 initiat\$3) same (plat\$3 electroplat\$3)	US-PGPUB; USPAT; EPO; JPO	OR	ON	2005/05/12 17:19
S9	1349	glass adj substrate same gate same line same electrode same pixel adj electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/12 18:14
S10	1279	S9 and (lcd liquid adj crystal adj display)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/12 18:14
S11	681	S10 not (@rlad>"20011102" @ad>"20011102")	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/12 18:14
S12	681	S11	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/12 18:14
S14	1349	glass adj substrate same gate same line same electrode same pixel adj electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 08:41
S15	1279	S14 and (lcd liquid adj crystal adj display)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 08:41
S16	681	S15 not (@rlad>"20011102" @ad>"20011102")	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/13 08:41
S17	681	S16	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/13 08:41
S18	297	S17 and (passivation insulat\$3 protect\$3) near7 pixel adj electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 10:11
S19	1349	glass adj substrate same gate same line same electrode same pixel adj electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 10:13
S20	1279	S19 and (lcd liquid adj crystal adj display)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 10:13

S21	681	S20 not (@rlad>"20011102" @ad>"20011102")	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/13 10:13
S22	681	S21	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/13 11:35
S23	14	S22 and pixel adj electrode adj3 ("on" "over" overlay\$3) adj2(passivation insulat\$3 dielectric protect\$3 silicon adj (nitride dioxide oxide) sin n>"sub. 4" sio2 siox "sio?sub.2")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 10:27
S24	14	S23 and pixel adj electrode adj3 ("on" "over" overlay\$3) adj2(passivation insulat\$3 dielectric protect\$3 silicon adj (nitride dioxide oxide) sin n>"sub. 4" sio2 siox "sio?sub.2")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 11:42
S25	1349	glass adj substrate same gate same line same electrode same pixel adj electrode	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 11:35
S26	1279	S25 and (lcd liquid adj crystal adj display)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 11:35
S27	681	S26 not (@rlad>"20011102" @ad>"20011102")	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/13 11:35
S28	681	S27	US-PGPUB; USPAT; EPO; JPO	OR	OFF	2005/05/13 11:39
S29	430	S28 and (pattern\$3 etch\$3) same line same electrode	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	ON	2005/05/13 11:44
S30	14	S29 and pixel adj electrode adj3 ("on" "over" overlay\$3) adj2(passivation insulat\$3 dielectric protect\$3 silicon adj (nitride dioxide oxide) sin n>"sub. 4" sio2 siox "sio?sub.2")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 11:42
S31	14	S30 and (pattern\$3 etch\$3) same line same electrode	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	ON	2005/05/13 11:47

S32	9	S30 and (pattern\$3 etch\$3) same gate adj3 line same gate adj electrode	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	ON	2005/05/13 11:58
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